

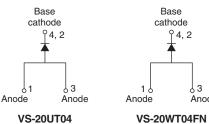
Vishay Semiconductors

High Performance Schottky Generation 5.0, 20 A





D-PAK(TO-252AA)



| PRODUCT SUMMARY | | | | |
|----------------------------------|---------------------------------------|--|--|--|
| Package | D-PAK (TO-252AA), I-PAK (TO-251AA) | | | |
| I _{F(AV)} | 20 A | | | |
| V _R | 45 V | | | |
| V _F at I _F | 0.53 V | | | |
| I _{RM} max. | 7 mA at 125 °C | | | |
| T _J max. | 175 °C | | | |
| Diode variation | Single die | | | |
| E _{AS} | 108 mJ | | | |

Note

 $\bullet~$ VF measured at 125 °C, connecting 2 anode pins

FEATURES

- 175 °C high performance Schottky diode
- · Very low forward voltage drop
- · Extremely low reverse leakage
- Optimized V_F vs. I_R trade off for high efficiency
- Increased ruggedness for reverse avalanche capability
- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- · Specific for PV cells bypass diode
- High efficiency SMPS
- High frequency switching
- Output rectification
- · Reverse battery protection
- Freewheeling
- DC/DC systems
- Increased power density systems

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-----------------------------------|--|-------------|-------|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | |
| V _{RRM} | | 45 | V | | |
| V _F | 20 Apk, T _J = 125 °C (typical, measured connecting 2 anode pins) | 0.480 | V | | |
| T _J | Range | - 55 to 175 | °C | | |

| VOLTAGE RATINGS | | | | |
|----------------------------|---------|------------------------|--------------------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VS-20UT04 VS-20WT04FN | UNITS |
| Maximum DC reverse voltage | V_{R} | T _J = 25 °C | 45 | V |

VS-20UT04, VS-20WT04FN

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| ABSOLUTE MAXIMUM RATINGS | | | | | |
|---------------------------------|--------------------|---|---|---|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| Maximum average forward current | I _{F(AV)} | 50 % duty cycle at T _C = 153 °C, rectangular waveform | | 20 | Α |
| Maximum peak one cycle | | 5 µs sine or 3 µs rect. pulse | Following any rated load condition and with rated | 900 | Δ. |
| non-repetitive surge current | IFSM | 10 ms sine or 6 ms rect. pulse | V _{RRM} applied ⁽¹⁾ | 220 | A |
| Non-repetitive avalanche energy | E _{AS} | $T_J = 25 ^{\circ}\text{C}, I_{AS} = 7 \text{A}, L = 4.4 \text{mH}$ | | 108 | mJ |
| Repetitive avalanche current | I _{AR} | Limited by frequency of operation and time pulse duration so that $T_J < T_J$ max. I_{AS} at T_J max. as a function of time pulse | | I _{AS} at T _J max. | Α |

Note

(1) Measured connecting 2 anode pins

| ELECTRICAL SPECIFICATIONS | | | | | | |
|--------------------------------|-----------------------------------|--|---------------------------------------|-------|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | TYP. | MAX. | UNITS |
| | V _{FM} ⁽¹⁾⁽²⁾ | 10 A | T _J = 25 °C | 0.505 | 0.540 | V |
| Forward voltage drop | | 20 A | | 0.570 | 0.610 | |
| Forward voltage drop | | 10 A | - T _J = 125 °C | 0.415 | 0450 | |
| | | 20 A | | 0.520 | 0.580 | |
| Reverse leakage current | I _{RM} ⁽¹⁾ | T _J = 25 °C | V _R = Rated V _R | - | 100 | μA |
| | | T _J = 125 °C | | - | 7 | mA |
| Junction capacitance | C _T | $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C | | 1900 | - | pF |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | | - | - | nH |
| Maximum voltage rate of change | dV/dt | Rated V _R | | - | 10 000 | V/µs |

Notes

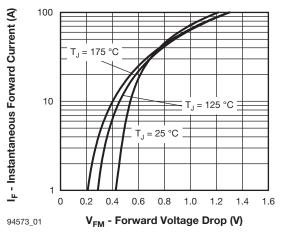
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

(2) Only 1 anode pin connected

| THERMAL - MECHANICAL SPECIFICATIONS | | | | |
|--|-----------------------------------|------------------|-------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | - 55 to 175 | °C |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation | 1.2 | °C/W |
| Typical thermal resistance, case to heatsink | R _{thCS} | | 0.3 | C/VV |
| Approximate weight | | | 2 | g |
| Approximate weight | | | 0.07 | oz. |
| Modern device | | Case style I-PAK | 20U | T04 |
| Marking device | | Case style D-PAK | 20WT04FN | |



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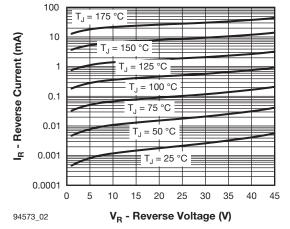


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

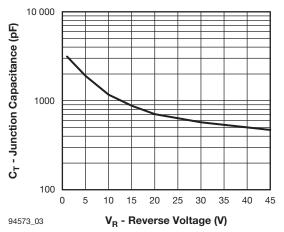


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

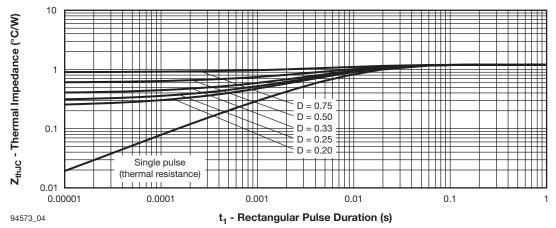
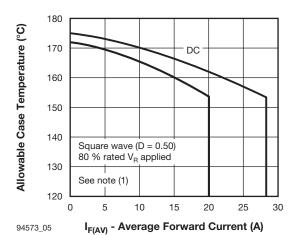


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





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15 90° 90° RMS limit 10 0 5 10 15 20 25 30

180°

20

94573_06

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

I_{F(AV)} - Average Forward Current (A)
Fig. 6 - Forward Power Loss Characteristics

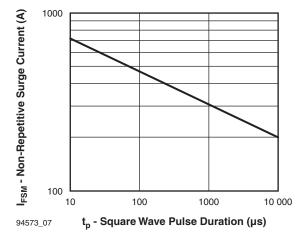


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

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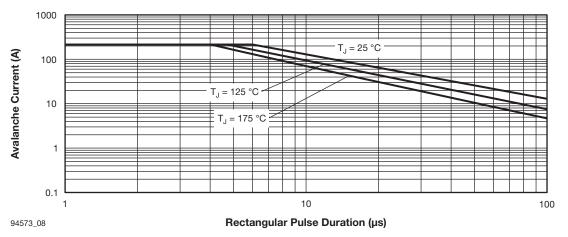


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

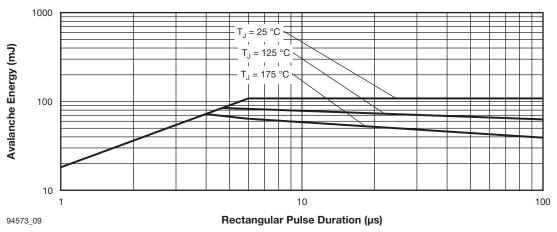


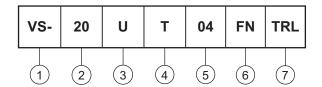
Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)



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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (20 A)

3 - Package:

• U = I-PAK

• W = D-PAK

4 - T = Trench

5 - Voltage code (45 V)

6 - TO-252AA (D-PAK)

7 - D-PAK, I-PAK:

None = Tube (75 pieces)

D-PAK only:

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

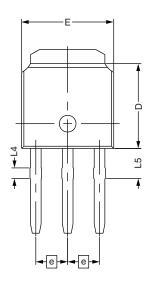
| LINKS TO RELATED DOCUMENTS | | | | | |
|------------------------------------|------------------|--------------------------|--|--|--|
| Dimensions | I-PAK (TO-251AA) | www.vishay.com/doc?95024 | | | |
| Differsions | D-PAK (TO-252AA) | www.vishay.com/doc?95448 | | | |
| Down and the state of the state of | I-PAK (TO-251AA) | www.vishay.com/doc?95025 | | | |
| Part marking information | D-PAK (TO-252AA) | www.vishay.com/doc?95059 | | | |
| Packaging information | | www.vishay.com/doc?95033 | | | |
| SPICE model | | www.vishay.com/doc?95027 | | | |

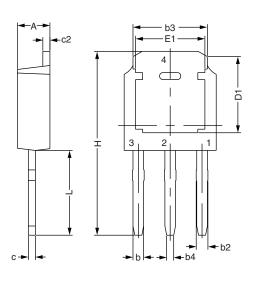


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I-PAK - S

DIMENSIONS FOR I-PAK - S in millimeters





| SYMBOL | DIMENSIONAL REQUIREMENTS | | | | |
|---------|--------------------------|-------|-------|--|--|
| STWIBOL | MIN. | NOM. | MAX. | | |
| E | 6.40 | 6.60 | 6.70 | | |
| L | 3.98 | 4.13 | 4.28 | | |
| L4 | 0.66 | 0.76 | 0.86 | | |
| L5 | 1.96 | 2.16 | 2.36 | | |
| D | 6.00 | 6.10 | 6.20 | | |
| Н | 11.05 | 11.25 | 11.45 | | |
| b | 0.64 | 0.76 | 0.88 | | |
| b2 | 0.77 | 0.84 | 1.14 | | |
| b3 | 5.21 | 5.34 | 5.46 | | |
| b4 | 0.41 | 0.51 | 0.61 | | |
| е | 2.286 BSC | | | | |
| А | 2.20 | 2.30 | 2.38 | | |
| С | 0.40 | 0.50 | 0.60 | | |
| c2 | 0.40 | 0.50 | 0.60 | | |
| D1 | 5.30 | - | - | | |
| E1 | 4.40 | - | - | | |



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